Attorney Docket No: SEMT116049

Group Art Unit: 2823

February 4, 1998 Examiner: D.M. Collins

METHOD FOR FILLING RECESSED MICRO-STRUCTURES WITH

METALLIZATION IN THE PRODUCTION OF A MICROELECTRONIC

DEVICE

Application No.: 09/018,783

Filed:

Title:

T.L. Ritzdorf et al.

<u>AMENDMENT</u>

Seattle, Washington 98101

June 13, 2001

TO THE COMMISSIONER FOR PATENTS:

Responsive to the Office Action mailed in the immediate prior application on October 4, 2000, please amend the above continued prosecution application as follows:

In the Claims:

Amend claims in accordance with the attached markup, and cancel Claims 2, 5, 18-23. All pending claims as thusly amended follow:

(Amended) A method for filling recessed microstructures at a surface of a 1. semiconductor workpiece with copper metal comprising:

depositing copper into the recessed micro-structures using an electrochemical process generating copper grains that are sufficiently small so as to substantially fill the recessed microstructures; and

subjecting the surface of the semiconductor workpiece with the deposited copper to an elevated temperature annealing process at a temperature below about 100 degrees Celsius for a time period that is sufficient to increase the grain size of the deposited copper.

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LAW OFFICES OF CHRISTENSEN O'CONNOR JOHNSON KINDNESSPILE 1420 Fifth Avenue Suite 2800 Seattle, Washington 98101 206.682.8100